

### Features:

- 650V Schottky Diode
- Zero Reverse Recovery Current
- High Frequency Operation
- Positive Temperature Coefficient
- Temperature independent Switching

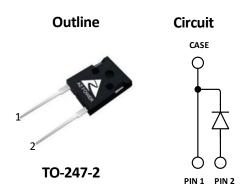
### **Benefits:**

- Unipolar Rectifier
- Minimal switching loss
- Higher Efficiency
- Low cooling requirement

Symbol	Value	Unit	
$V_{RRM}$	650	V	
I <sub>F</sub> (Tc=148ºC)	20	А	
Qc	65	nC	

# Applications:

- Switch Mode Power Supply
- Booster diodes in PFC, DC/DC
- AC/DC converters



## **Maximum Ratings**

Symbol	Parameter	Value	Unit	Test Conditions
$V_R$	DC Peak Reverse Voltage	650	V	T <sub>J</sub> =25°C
$V_{RRM}$	Repetitive Peak Reverse Voltage	650	V	T <sub>J</sub> =25°C
$V_{RSM}$	Surge Peak Reverse Voltage	650	V	T <sub>J</sub> =25°C
I <sub>F</sub>	Continuous Forward Current	58 26.5 20	А	T <sub>C</sub> =25°C T <sub>C</sub> =135°C T <sub>C</sub> =148°C
I <sub>FRM</sub>	Repetitive Peak Forward Surge Current	176 160	А	$T_{\text{C}}$ =25°C, $T_{\text{P}}$ =10ms, Half Sine Wave Tc=125°C, $T_{\text{P}}$ =10ms, Half Sine Wave
I <sub>FSM</sub>	Non-Repetitive Peak Forward Surge Current	236 212	А	$T_C$ =25°C, $T_P$ =10ms, Half Sine Wave Tc=125°C, $T_P$ =10ms, Half Sine Wave
P <sub>D</sub>	Power Dissipation	200 67	W	T <sub>C</sub> =25°C Tc=125°C
$T_{J,max}$	Operating Junction Temperature	175	°C	
T <sub>stg</sub>	Storage Temperature Range	-55 to 175	°C	

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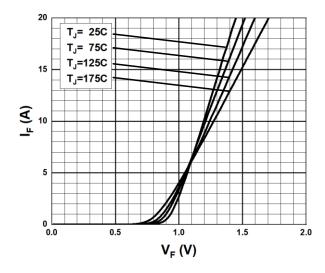
## Thermal characteristics

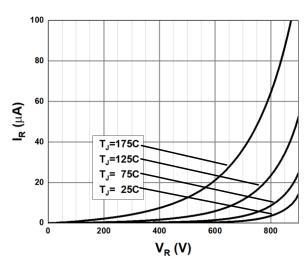
Symbol	Parameter	Min.	Тур.	Max.	Unit
R <sub>thJC</sub>	Thermal Resistance		0.75		°C/W

### **Electrical Characteristics**

Symbol Parameter	Value		11	Total Constitutions		
	Parameter	Min.	Тур.	Max.	Unit	Test Conditions
$V_{DC}$	DC Blocking Voltage	650			V	I <sub>R</sub> =500μA, T <sub>J</sub> =25°C
V	Forward Voltage		1.45	1.7	٧	I <sub>F</sub> =20A, T <sub>J</sub> =25°C
V <sub>F</sub>	Forward Voltage		1.75	2.0		I <sub>F</sub> =20A, T <sub>J</sub> =175°C
I <sub>R</sub> Reve	Reverse Current		2	50	μΑ	V <sub>R</sub> =650V, T <sub>J</sub> =25°C
	Reverse Current		50	300		V <sub>R</sub> =650V, T <sub>J</sub> =175°C
Q <sub>C</sub> Total Capacitive Char	Tatal Canacitina Chana		65		nC	I <sub>F</sub> =20A, dI/dt=600A/μs
	lotal Capacitive Charge					T <sub>J</sub> =25°C, V <sub>R</sub> =400V
С	Total Capacitance		796		pF	V <sub>R</sub> =1V, T <sub>J</sub> =25°C, f=1 MHz
			157			V <sub>R</sub> =200V, T <sub>J</sub> =25°C, f=1 MHz
			138			V <sub>R</sub> =400V, T <sub>J</sub> =25°C, f=1 MHz

## **Typical Performance**





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Fig. 1 Forward Characteristics

### Fig. 2 Reverse Characteristics

## **Typical Performance**

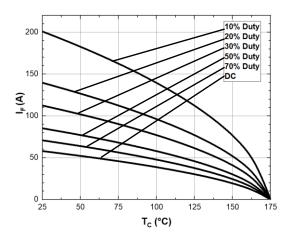


Fig. 3 Current Derating

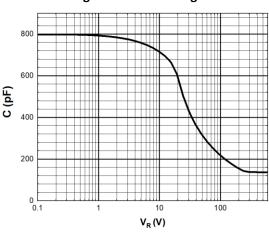


Fig. 5 Capacitance vs. Reverse Voltage

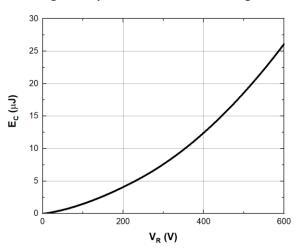


Fig. 7 Capacitance stored Energy

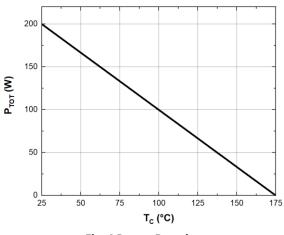


Fig. 4 Power Derating

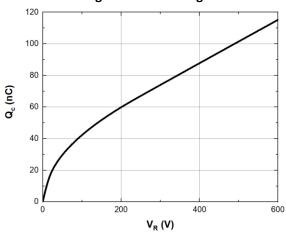


Fig. 6 Recovery Charge vs. Reverse Voltage

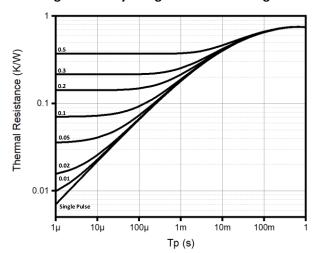
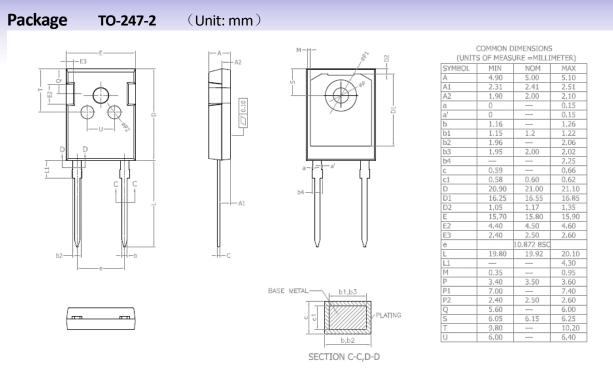


Fig. 8 Thermal Impedance

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